

3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

Typical Applications

The HMC629ALP4E is ideal for:

- Cellular/3G Infrastructure
- WiBro / WiMAX / 4G
- Microwave Radio & VSAT
- Test Equipment and Sensors
- IF & RF Applications

Features

3 dB LSB Steps to 45 dB

Power-Up State Selection

Low Insertion Loss: 2.25 dB

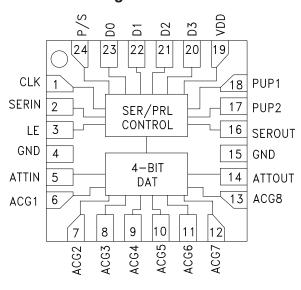
TTL/CMOS Compatible, Serial, Parallel or Latched Parallel Control

±0.25 dB Typical Step Error

Single +3V or +5V Supply

24 Lead 4x4mm SMT Package: 16mm²

Functional Diagram



General Description

The HMC629ALP4E is a broadband 4-bit GaAs IC Digital Attenuator in a low cost leadless SMT package. This versatile digital attenuator incorporates off-chip AC ground capacitors for near DC operation, making it suitable for a wide variety of RF and IF applications. The dual mode control interface is CMOS/TTL compatible, and accepts either a three wire serial input or a 4-bit parallel word. The HMC629ALP4E is housed in a RoHS compliant 4x4 mm QFN leadless package, and requires no external matching components.

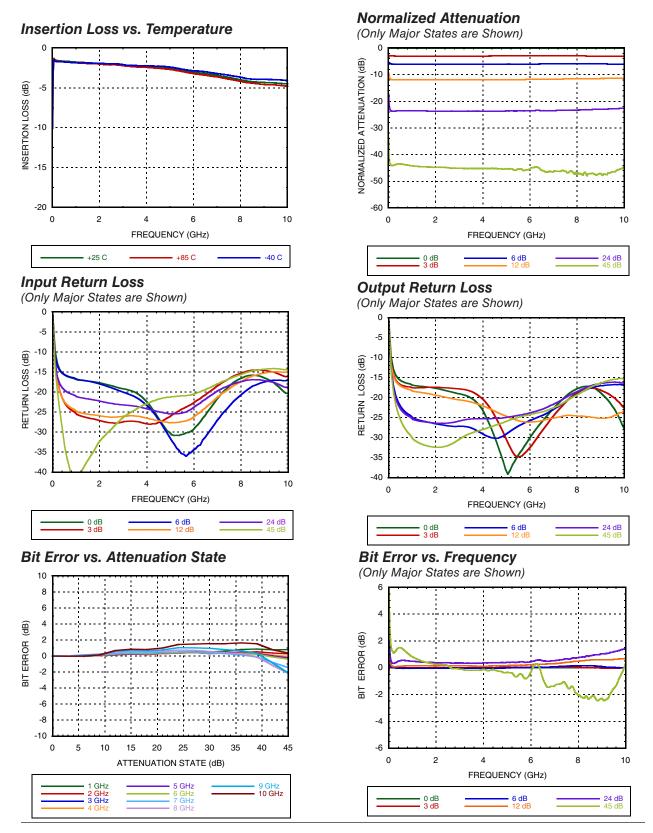
Electrical Specifications,

 $T_A = +25^{\circ}\text{C}$, 50 Ohm System, with Vdd = +5V & VctI = 0/+5V (Unless Otherwise Noted)

| Parameter | Frequency (GHz) | Min. | Тур. | Max. | Units |
|--|--------------------------|--|------------------------------|----------|----------|
| Insertion Loss | DC - 6 GHz 6 - 10 GHz | | 2.25 3.75 | | dB dB |
| Attenuation Range | DC - 10 GHz | | 45 | | dB |
| Return Loss (ATTIN, ATTOUT, All Atten. States) | DC - 6 GHz 6 - 10 GHz | | 17 15 | | dB |
| Attenuation Accuracy: (Referenced to Insertion Loss) All Attenuation States | DC - 6 GHz 6 - 10 GHz | ± (0.4 + 4% of Atten. Setting) Max. ± (0.5 + 5% of Atten. Setting) Max. | | dB dB | |
| Input Power for 0.1 dB Compression | DC - 10 GHz | | 30 at Vdd=5V 25 at Vdd=3V | | dBm |
| Input Third Order Intercept Point (Two-Tone Input Power = 20 dBm Each Tone) | DC - 10 GHz | | 55 | | dBm |
| Switching Speed | | | | | |
| tRise, tFall (10 / 90% RF) tON , tOFF (50% LE to 10 / 90% RF) | DC - 10 GHz | | 100 120 | | ns ns |



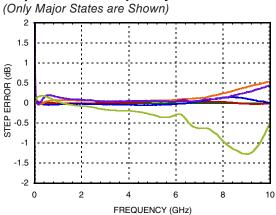
3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz



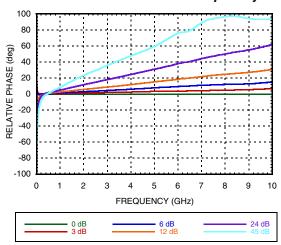


3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

Step Error vs. Frequency

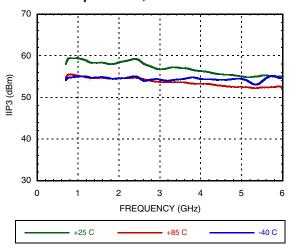


Normal Relative Phase vs. Frequency

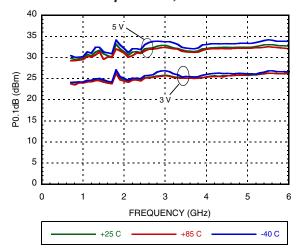


IIP3 vs. Temperature, IL State

0 dB 3 dB



P0.1dB vs. Temperature, IL State





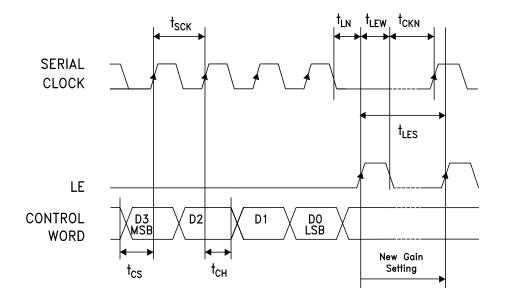
3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

Serial Control Interface

The HMC629ALP4E contains a 3-wire SPI compatible digital interface (SERIN, CLK, LE). The serial control interface is activated when P/S is kept high. The 4-bit serial word must be loaded MSB first. The positive-edge sensitive CLK and LE requires clean transitions. If mechanical switches are used, sufficient debouncing should be provided. When LE is high, 4-bit data in the serial input register is transferred to the attenuator. When LE is high CLK is masked to prevent data transition during output loading.

When P/S is low, 3-wire SPI interface inputs (SERIN, CLK, LE) are disabled and the input register is loaded with parallel digital inputs (D0-D3). When LE is high, 4-bit parallel data changes the state of the part per truth table.

For all modes of operations, the state will stay constant while LE is kept low.





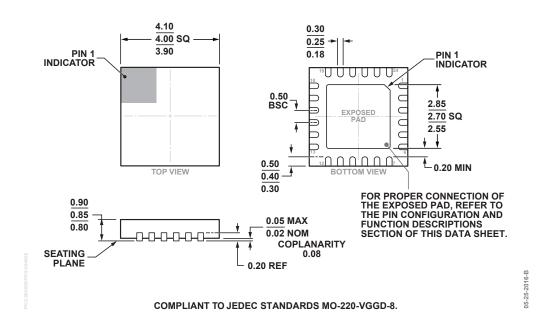
3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

Absolute Maximum Ratings

| RF Input Power (DC - 6 GHz) | 28 dBm (T = +85 °C , Vdd= 5V) |
|--|-------------------------------|
| Digital Inputs (Data, Shift Clock, Latch Enable & Serial Input) | -0.5 to Vdd +0.5V |
| Bias Voltage (Vdd) | 5.6V |
| Channel Temperature | 150 °C |
| Continuous Pdiss (T = 85 °C) (derate 14 mW/°C above 85 °C) [1] | 0.88 W |
| Thermal Resistance | 75 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| ESD Sensitivity (HBM) | Class 1A |



Outline Drawing



Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking [2] |
|-------------|--|---------------|---------------------|----------------------|
| HMC629ALP4E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL3 ^[1] | <u>H629A</u> XXXX |

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX



3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

| Parameter | Typ.(ns) |
|--|----------|
| Min. serial period, t _{sck} | 100 |
| Control set-up time, t _{cs} | 20 |
| Control hold-time, t _{CH} | 20 |
| LE setup-time, t _{LN} | 10 |
| Min. LE pulse width, t _{LEW} | 10 |
| Min LE pulse spacing, t _{LES} | 630 |
| Serial clock hold-time from LE, t _{CKN} | 10 |
| Hold Time, t _{PH.} | 0 |
| Latch Enable Minimum Width, t _{LEN} | 10 |
| Setup Time, t _{PS} | 2 |

†_{PS} †_{PH}

TLEN

D0-D3

Timing Diagram (Latched Parallel Mode)

Parallel Mode (Direct Parallel Mode & Latched Parallel Mode)

Note: The parallel mode is enabled when P/S is set to low.

Direct Parallel Mode - The attenuation state is changed by the Control Voltage Inputs directly. The LE (Latch Enable) must be at a logic high to control the attenuator in this manner.

Latched Parallel Mode - The attenuation state is selected using the Control Voltage Inputs and set while the LE is in the Low state. The attenuator will not change state while LE is Low. Once all Control Voltage Inputs are at the desired states the LE is pulsed. See timing diagram below for reference.

Power-Up States

If LE is set to logic LOW at power-up, the logic state of PUP1 and PUP2 determines the power-up state of the part per PUP truth table. If the LE is set to logic HIGH at power-up, the logic state of D3-D0 determines the power-up state of the part per truth table. The attenuator latches in the desired power-up state approximately 200 ms after power-up.

Power-On Sequence

The ideal power-up sequence is: GND, VDD, digital inputs, RF inputs. The relative order of the digital inputs are not important as long as they are powered after VDD / GND

Bias Voltage

| Vdd (Vdc) | Idd (Typ.) (mA) | |
|-----------|-----------------|--|
| 5 | 1.5 | |

Control Voltage Table

| State | Vdd = +3V | Vdd = +5V |
|-------|--------------------|--------------------|
| Low | 0 to 0.5V at <1 μA | 0 to 0.8V at <1 μA |
| High | 2 to 3V at <1 μA | 2 to 5V at <1 μA |

PUP Truth Table

PARALLEL CONTROL

| LE | PUP1 | PUP2 | Attenuation State |
|----|------|------|-------------------|
| 0 | 0 | 0 | 45 dB |
| 0 | 1 | 0 | 45 dB |
| 0 | 0 | 1 | 45 dB |
| 0 | 1 | 1 | Insertion Loss |
| 1 | Х | Х | 0 to 45 dB |

Note: This truth table is valid only when P/S = 0. Power-Up with LE= 1 provides direct parallel operation with D0 - D3.

Truth Table

| Control Voltage Input | | | Attenuation State | |
|-----------------------|------|------|-------------------|-------------------|
| D3 | D2 | D1 | D0 | Attenuation State |
| High | High | High | High | Reference I.L. |
| High | High | High | Low | 3 dB |
| High | High | Low | High | 6 dB |
| High | Low | High | High | 12 dB |
| Low | High | High | High | 24 dB |

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.



3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

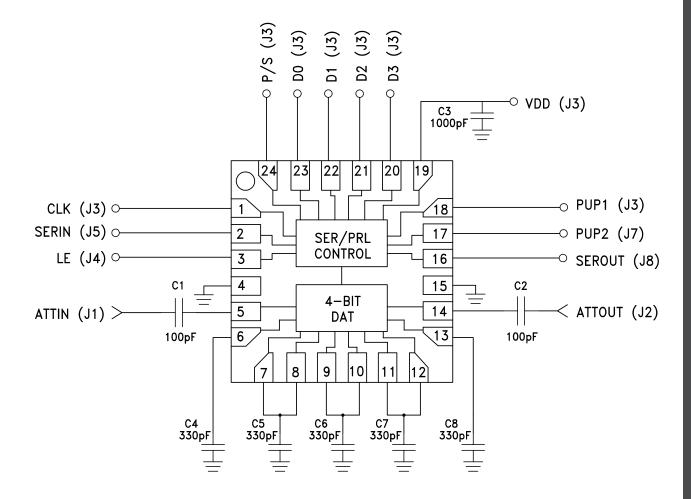
Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|------------|------------------|--|---------------------|
| 24 1 2 | P/S CLK SERIN LE | See truth table, control voltage table and timing diagram. | P/S CLK SERIN LE |
| 4, 15 | GND | These pins and package bottom must be connected to RF/DC ground. | ⊖ GND = |
| 5, 14 | ATTIN, ATTOUT | These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required. Select value based on lowest frequency of operation. | ATTIN, O-CY |
| 6 - 13 | ACG1 - ACG6 | External capacitors to ground are required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible. See Application Circuit. | |
| 16 | SEROUT | Serial input data delayed by 4 clock cycles. | VDD O SEROUT |
| 17, 18 | PUP2, PUP1 | See truth table, control voltage | PUP2, PUP1 |
| 20 - 23 | D3, D2, D1, D0 | table and timing diagram. | DO-D3 |
| 19 | VDD | Supply voltage | |



3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

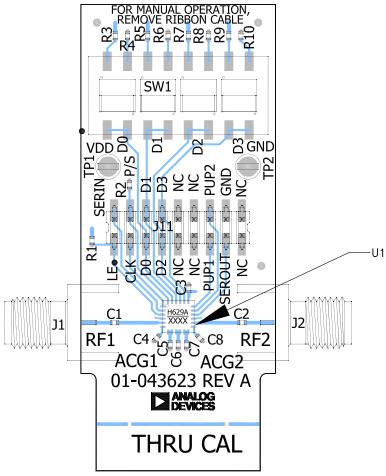
Application Circuit





3 dB LSB GaAs MMIC 4-BIT DIGITAL ATTENUATOR, DC - 10GHz

Evaluation PCB



v01.0716

List of Materials for Evaluation EV1HMC629ALP4E [1]

| Item | Description | |
|----------|--------------------------------|--|
| J1, J2 | PCB Mount SMA Connector | |
| TP1, TP2 | DC Pin | |
| J11 | 18 Pin DC Connector | |
| C1 - C2 | 100 pF, capacitor 0402 pkg | |
| C3 | 1000 pF, capacitor 0402 pkg | |
| C4 - C8 | 330 pF, capacitor 0402 pkg | |
| R1 - R10 | 100 kOhm Resistor, 0402 Pkg. | |
| SW1 | SPDT 4 Position DIP Switch | |
| U1 | HMC629ALP4E Digital Attenuator | |
| PCB [2] | 01-043623 Rev A Evaluation PCB | |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Development Tools category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below:

MAAM-011117 MAAP-015036-DIEEV2 EV1HMC1113LP5 EV1HMC6146BLC5A EV1HMC637ALP5 EVAL-ADG919EBZ ADL5363EVALZ LMV228SDEVAL SKYA21001-EVB SMP1331-085-EVB EV1HMC618ALP3 EVAL01-HMC1041LC4 MAAL-011111-000SMB
MAAM-009633-001SMB MASW-000936-001SMB 107712-HMC369LP3 107780-HMC322ALP4 SP000416870 EV1HMC470ALP3
EV1HMC520ALC4 EV1HMC244AG16 MAX2614EVKIT# 124694-HMC742ALP5 SC20ASATEA-8GB-STD MAX2837EVKIT+
MAX2612EVKIT# MAX2692EVKIT# EV1HMC629ALP4E SKY12343-364LF-EVB 108703-HMC452QS16G EV1HMC863ALC4
EV1HMC427ALP3E 119197-HMC658LP2 EV1HMC647ALP6 ADL5725-EVALZ 106815-HMC441LM1 EV1HMC1018ALP4
UXN14M9PE MAX2016EVKIT EV1HMC939ALP4 MAX2410EVKIT MAX2204EVKIT+ EV1HMC8073LP3D SIMSA868-DKL
SIMSA868C-DKL SKY65806-636EK1 SKY68020-11EK1 SKY67159-396EK1 SKY66181-11-EK1 SKY65804-696EK1